Vishay Semiconductors



γ3

Anode

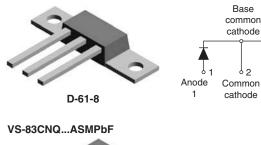
2

63

Anode

2

VS-83CNQ...APbF



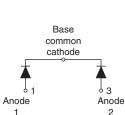
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D-61-8-SM

VS-83CNQ...ASLPbF





62

Common

cathode

01

Anode

1

D-61-8-SL

PRODUCT SUMMARY						
Package	D-61					
I <sub>F(AV)</sub>	2 x 40 A					
V <sub>R</sub>	80 V, 100 V					
V <sub>F</sub> at I <sub>F</sub>	0.81					
I <sub>RM</sub> max.	35 mA at 125 °C					
T <sub>J</sub> max.	175 °C					
Diode variation	Common cathode					
E <sub>AS</sub>	15 mJ					

### FEATURES

- 175 °C T<sub>J</sub> operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- High power discrete
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- New fully transfer-mold low profile, small footprint, high current package
- Through-hole versions are currently available for use in lead (Pb)-free applications ("PbF" suffix)
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### Note

\* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non-RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details.

### DESCRIPTION

The center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	80	А					
V <sub>RRM</sub>		80, 100	V					
I <sub>FSM</sub>	$t_p = 5 \ \mu s \ sine$	7000	А					
V <sub>F</sub>	40 $A_{pk}$ , $T_J$ = 125 °C (per leg)	0.67	V					
TJ	Range	-55 to +175	°C					

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-83CNQ080APbF	VS-83CNQ100APbF	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	80	100	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	00	100	V	

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1

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS		
Maximum average forward current See fig. 5	$I_{F(AV)}$ 50 % duty cycle at T <sub>C</sub> = 132 °C, rectangular waveform		80			
Maximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated	7000	A	
surge current per leg I <sub>FS</sub> See fig. 7		10 ms sine or 6 ms rect. pulse	load condition and with rated V <sub>RRM</sub> applied	720		
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 30 mH		15	mJ	
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical 1		А		

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS VALUES			UNITS	
	V <sub>FM</sub> <sup>(1)</sup>	40 A	T _ 25 °C	0.81	- V	
Maximum forward voltage drop per leg See fig. 1		80 A	T <sub>J</sub> = 25 °C	1.00		
		40 A	T <sub>.1</sub> = 125 °C	0.67		
		80 A	1j = 125 C	0.82		
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V - Reted V	1.5	- mA	
See fig. 2		T <sub>J</sub> = 125 °C	$V_{R} = Rated V_{R}$	35		
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		1400	pF	
Typical series inductance per leg	LS	Measured lead to lead 5 mm from package body 5.5		nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V/µ			V/µs	

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and stora temperature range	ge	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C	
Maximum thermal	per leg	R <sub>thJC</sub>	DC operation, see fig. 4	0.85		
resistance, junction to case	per package	nthJC	DC operation	0.42	°C/W	
Typical thermal resistance, case to heatsink (D-61-8 only)		R <sub>thCS</sub>	Mounting surface, smooth and greased Device flatness < 5 mils	0.30		
Approximate weight	An ana sina ata susialat			7.8	g	
Approximate weight				0.28	oz.	
Mounting torque	minimum		Recommended hardware 3M stainless screw	12 (10)	kgf · cm	
	maximum		Necommended hardware SWI stamless screw	24 (20)	(lbf · in)	
			Case style D 61	83CNQ	83CNQ080A	
Marking device			Case style D-61	83CNQ100A		
					83CNQ080ASM	
		Case style D-61-8-SM		83CNQ100ASM		
			Case style D 61 9 Cl	83CNQ080ASL		
			Case style D-61-8-SL		83CNQ100ASL	



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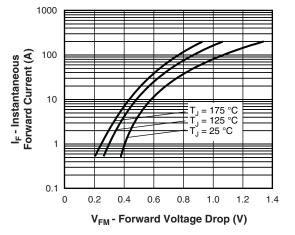


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

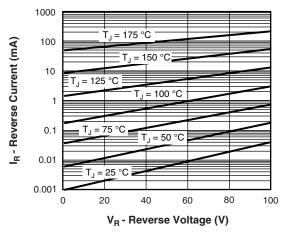


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

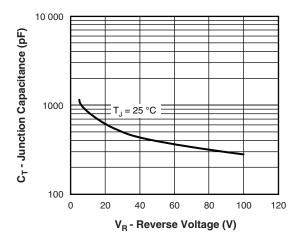
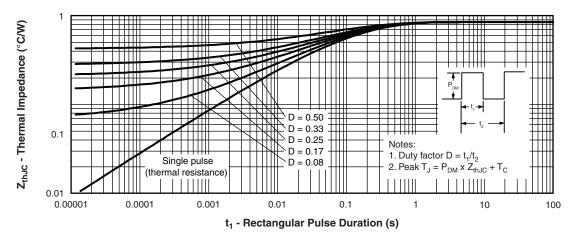
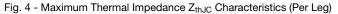


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)





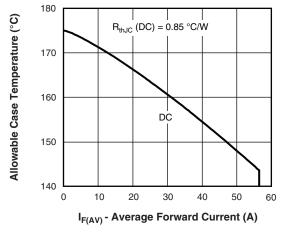
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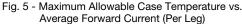
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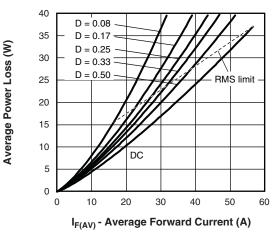


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

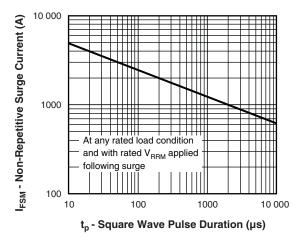


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

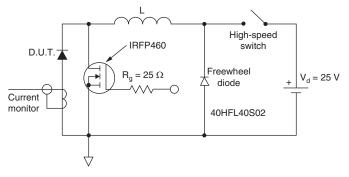


Fig. 8 - Unclamped Inductive Test Circuit

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### **ORDERING INFORMATION TABLE**

Device code	VS-	83	С	Ν	Q	100	Α	PbF
	1	2	3	4	5	6	7	8
	1 · 2 · 3 ·	Curr Circ C =	nay Sem rent ratii cuit confi commo	ng (80 A guratior	n:	oduct		
	4 ·	N =	kage: D-61 ottky "Q	" series				_
	6 · 7 ·	· Volt	age rati kage sty	ngs —			= 80 V 100 V	
		• A8	= D-61-8 SM = D- SL = D-6	- 61-8-SN	1			
	8.	• Pk	one = sta oF = lead	d (Pb)-fr	ee			

Standard pack quantity: A = 10 pieces; ASM/ASL = 20 pieces

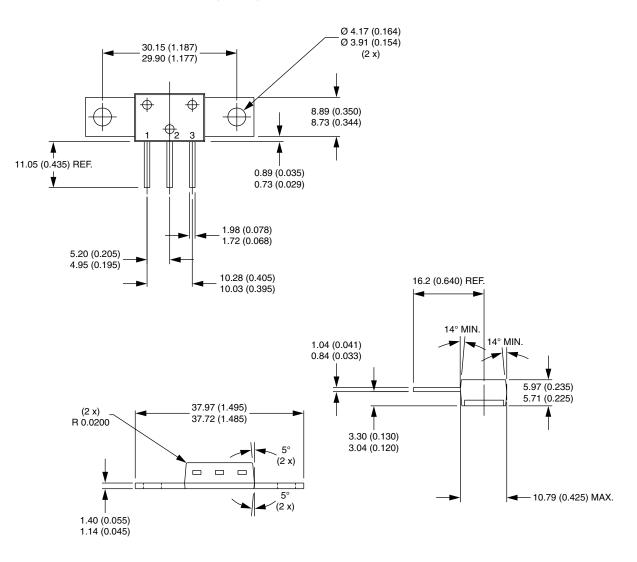
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95354				
Part marking information	www.vishay.com/doc?95356				
SPICE model	www.vishay.com/doc?95290				

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D-61-8, D-61-8-SM, D-61-8-SL

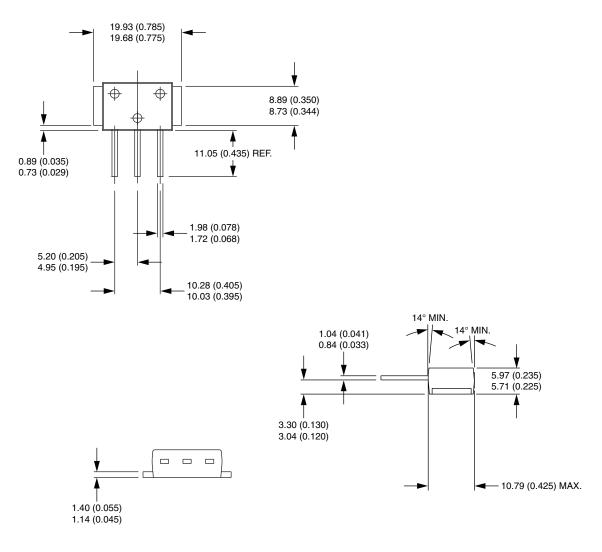
### DIMENSIONS - D-61-8 in millimeters (inches)





### DIMENSIONS - D-61-8-SM in millimeters (inches)

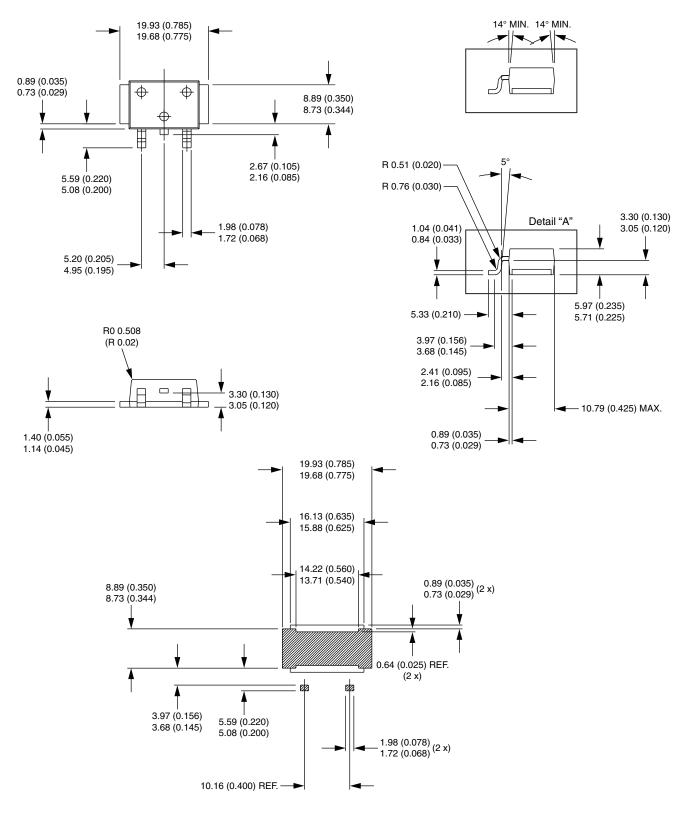
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### DIMENSIONS - D-61-8-SL in millimeters (inches)

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